



SEMIPACK® 5

Rectifier Diode Modules

SKKD 701

Features

- Heat transfer through aluminium nitride ceramic insulated metal baseplate
- Precious metal pressure contacts for high reliability
- UL recognized, file no. E63532

Typical Applications

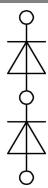
- Uncontrolled rectifiers for AC/AC converters
- Line rectifiers for transistorized AC motor controller
- Field supply for DC motors

1) see assembly instructions

2) screws must be lubricated

V_{RSM}	V_{RRM}	$I_{FRMS} = 1100 \text{ A}$ (maximum value for continuous operation) $I_{FAV} = 701 \text{ A}$ (sin. 180; $T_c = 100 \text{ }^\circ\text{C}$)
1300	1200	SKKD 701/12
1700	1600	SKKD 701/16
1900	1800	SKKD 701/18
2300	2200	SKKD 701/22 H4

Symbol	Conditions	Values	Units
I_{FAV}	sin. 180; $T_c = 100$ (85) $^\circ\text{C}$	701 (820)	A
I_{FSM}	$T_{vj} = 25 \text{ }^\circ\text{C}; 10 \text{ ms}$ $T_{vj} = 160 \text{ }^\circ\text{C}; 10 \text{ ms}$	25000 22500	A A
i^2t	$T_{vj} = 25 \text{ }^\circ\text{C}; 8,3 \dots 10 \text{ ms}$ $T_{vj} = 160 \text{ }^\circ\text{C}; 8,3 \dots 10 \text{ ms}$	3125000 2531250	A ² s A ² s
V_F	$T_{vj} = 25 \text{ }^\circ\text{C}; I_F = 2000 \text{ A}$	max. 1,25	V
$V_{(TO)}$	$T_{vj} = 160 \text{ }^\circ\text{C}$	max. 0,7	V
r_T	$T_{vj} = 160 \text{ }^\circ\text{C}$	max. 0,28	mΩ
I_{RD}	$T_{vj} = 160 \text{ }^\circ\text{C}; V_{RD} = V_{RRM}$	max. 50	mA
$R_{th(j-c)}$	cont.; per diode / per module sin. 180; per diode / per module rec. 120; per diode / per module	0,069 / 0,034 0,072 / 0,036 0,077 / 0,038	K/W K/W K/W
$R_{th(c-s)}$	per diode / per module	0,02 / 0,01	K/W
T_{vj}		- 40 ... + 160	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a.c. 50 Hz, r.m.s.; 1 s / 1 min.	3600 / 3000	V~
V_{isol}	a.c. 50 Hz, r.m.s.; 1 s / 1 min. for SKK... H4	4800 / 4000	V~
M_s	to heatsink	5 ± 15 % ¹⁾	Nm
M_t	to terminals	12 ± 15 % ²⁾	Nm
a		5 * 9,81	m/s ²
m	approx.	1400	g
Case		A 75b	



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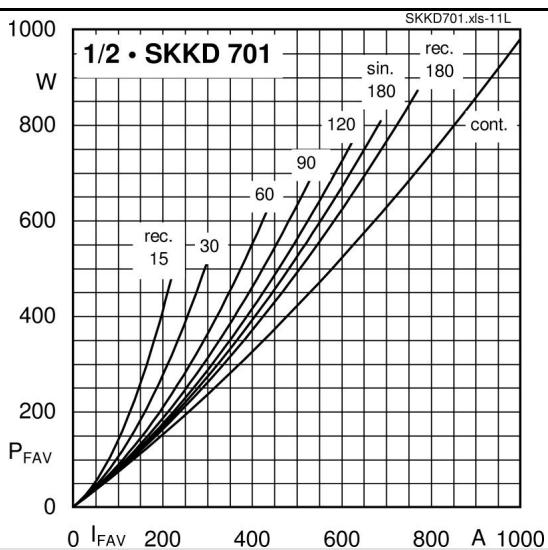


Fig. 11L Power dissipation per diode vs. forward current

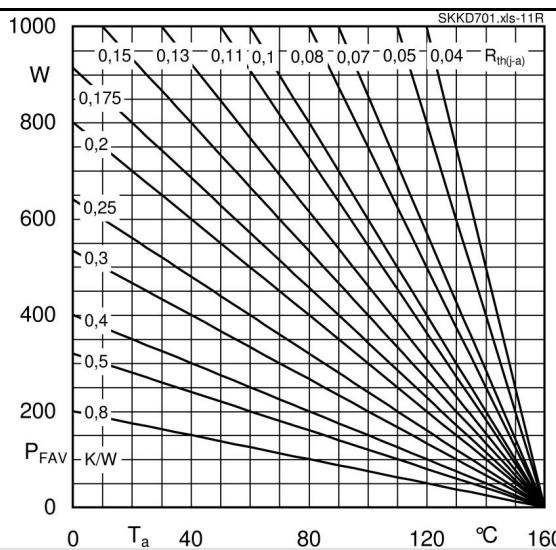


Fig. 11R Power dissipation per diode vs. ambient temperature

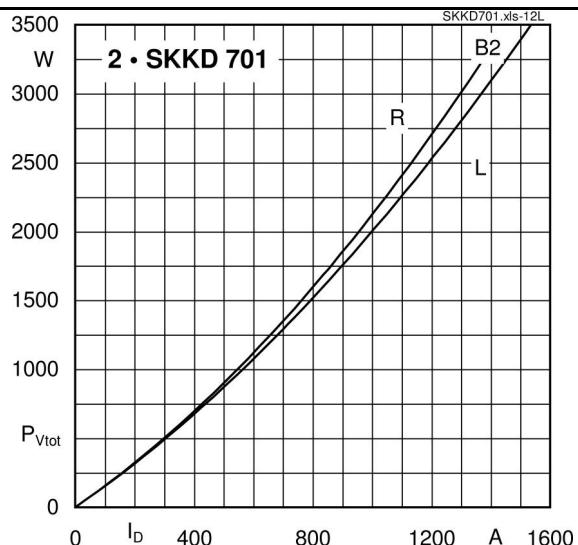


Fig. 12L Power dissipation of two modules vs. direct current

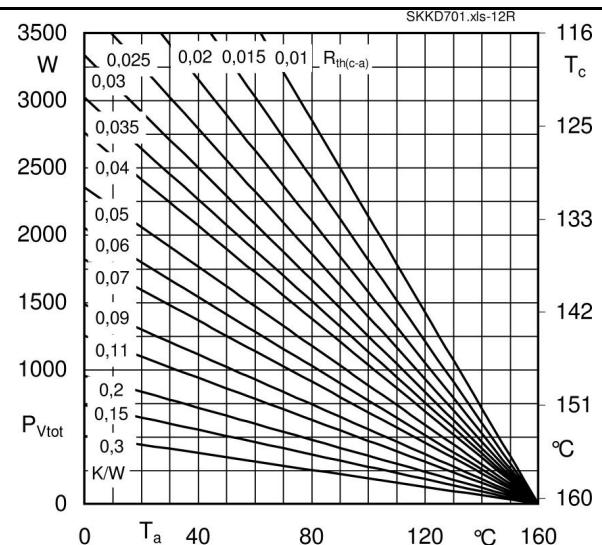


Fig. 12R Power dissipation of two modules vs. case temperature

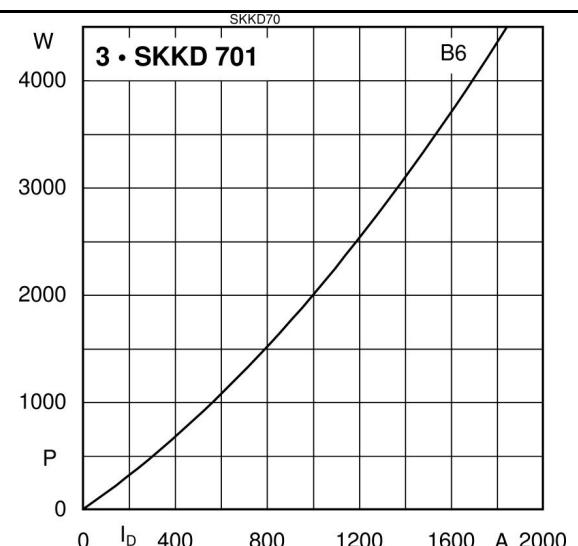


Fig. 13L Power dissipation of three modules vs. direct current

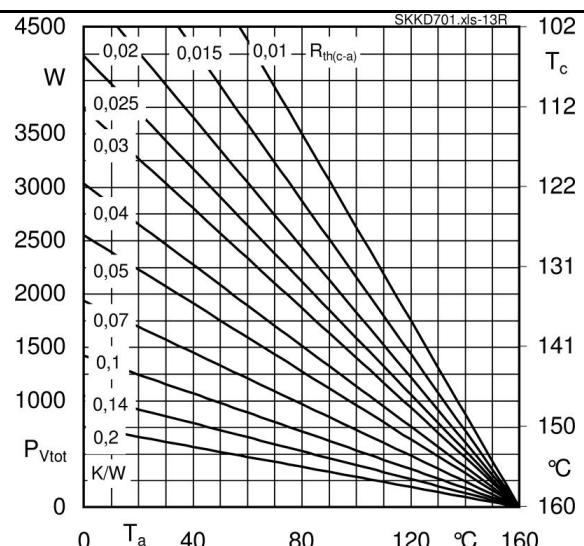


Fig. 13R Power dissipation of three modules vs. case temperature

SKKD 701 THYRISTOR BRIDGE,SCR,BRIDGE

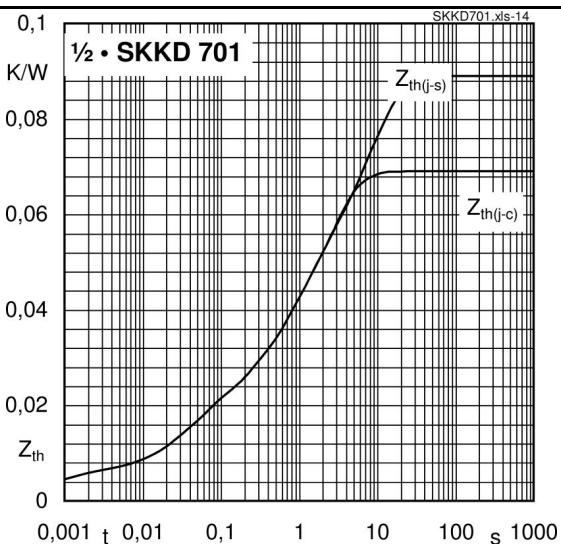


Fig. 14 Transient thermal impedance vs. time

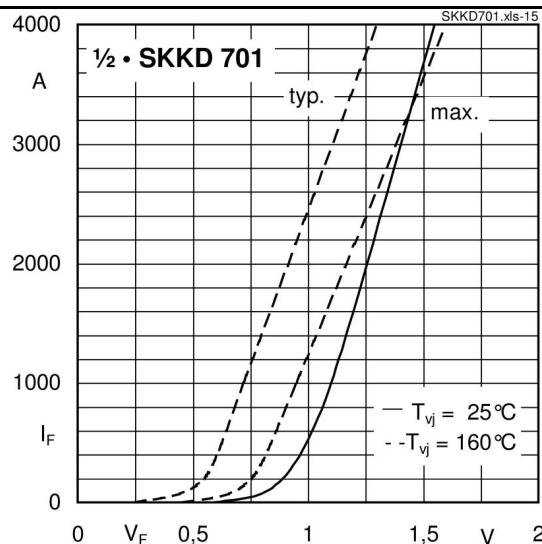


Fig. 15 Forward characteristics

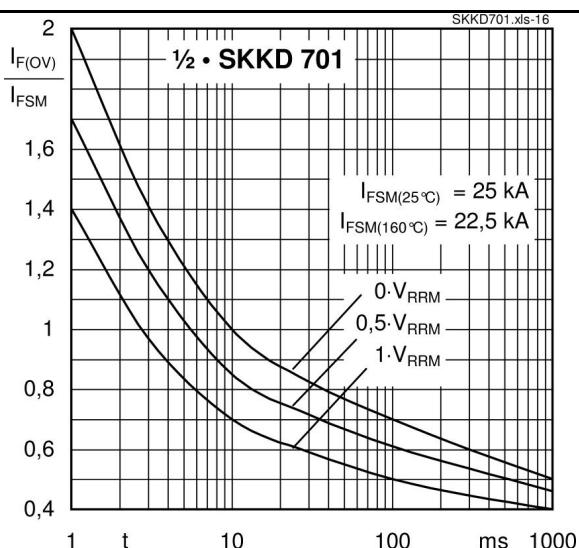
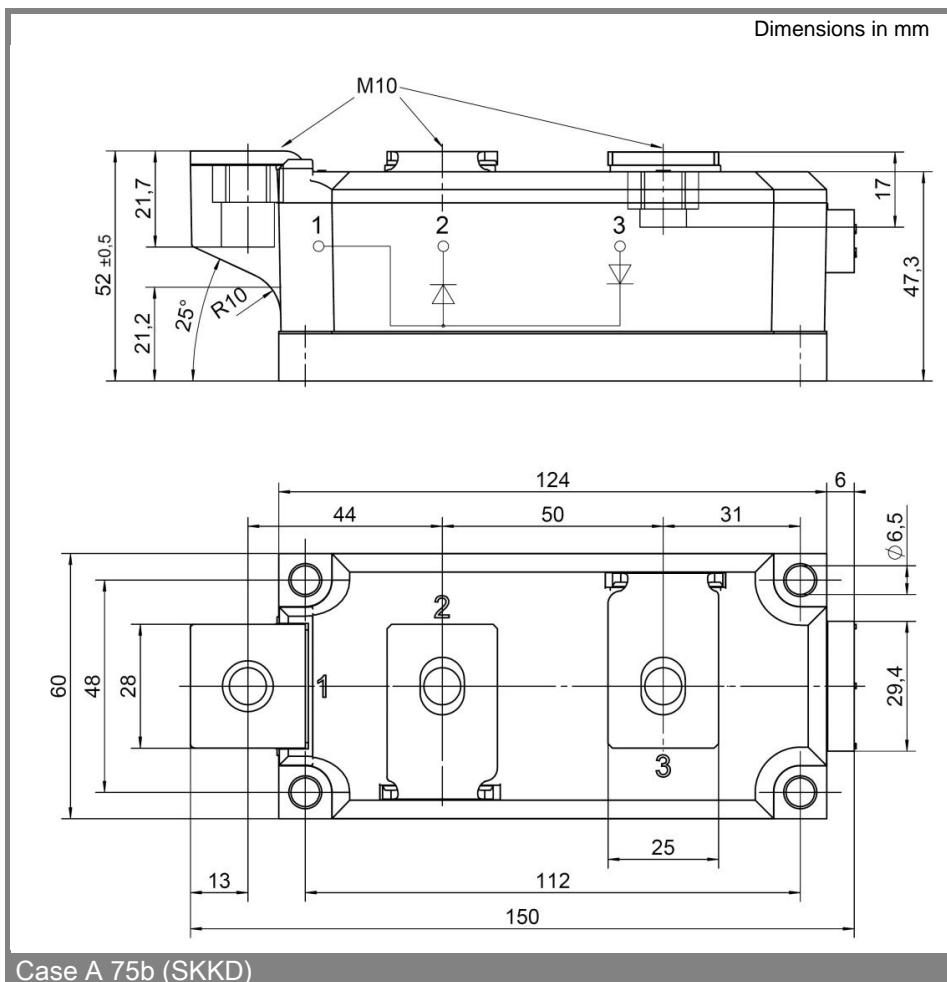


Fig. 16 Surge overload current vs. time



Case A 75b (SKKD)

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